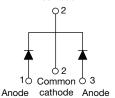
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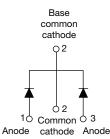
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High Performance Schottky Rectifier, 2 x 20 A





SHAY



VS-40CTQ045S-M3

VS-40CTQ045-1-M3

PRIMARY CHARACTERISTICS								
I _{F(AV)}	2 x 20 A							
V _R	45 V							
V _F at I _F	0.48 V							
I _{RM} typ.	115 mA at 125 °C							
T _J max.	150 °C							
E _{AS}	20 mJ							
Package	D ² PAK (TO-263AB), TO-262AA							
Circuit configuration	Common cathode							

FEATURES

- 150 °C T_J operation
- Center tap configuration
- Very low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This center tap Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS										
SYMBOL	MBOL CHARACTERISTICS VALUES									
I _{F(AV)}	Rectangular waveform	40	A							
V _{RRM}		45	V							
I _{FSM}	t _p = 5 μs sine	1240	A							
V _F	20 A_{pk} , T_J = 125 °C (per leg)	0.48	V							
TJ	Range	-55 to +150	C°							

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-40CTQ045S-M3 VS-40CTQ045-1-M3	UNITS					
Maximum DC reverse voltage	V _R	45	V					
Maximum working peak reverse voltage	V _{RWM}	45	V					

RoHS COMPLIANT HALOGEN FREE

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ABSOLUTE MAXIMUM RATINGS									
PARAMETER		SYMBOL	TEST COND	VALUES	UNITS				
Maximum average	per leg			20					
forward current See fig. 5	per device	I _{F(AV)}	50 % duty cycle at T _C = 116 °C	40	А				
Maximum peak one cycle no	e non-repetitive		5 µs sine or 3 µs rect. pulse	Following any rated load	1240	A			
surge current per leg See fig. 7		I _{FSM}	10 ms sine or 6 ms rect. pulse condition and with rated V _{RRM} applied		350				
Non-repetitive avalanche en	ergy per leg	E _{AS}	$T_J = 25 \text{ °C}, I_{AS} = 3 \text{ A}, L = 4.40 \text{ mH}$		20	mJ			
Repetitive avalanche curren	t per leg	I _{AR}	Current decaying linearly to zer Frequency limited by T_J maxim		3	А			

ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST C	ONDITIONS	VALUES	UNITS			
		20 A	– T _{.1} = 25 °C	0.53				
Maximum forward voltage drop per leg See fig. 1	V _{FM} ⁽¹⁾	40 A	1 = 25 0	0.68	V			
	VFM V	20 A	T _{.1} = 125 °C	0.48	V			
		40 A	1j=125 C	0.67				
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	3	mA			
Maximum reverse leakage current per leg		T _J = 125 °C		150				
Typical reverse leakage current	I _{RM} ⁽¹⁾	T _J = 125 °C	V _R = Rated V _R	115	mA			
Threshold voltage	V _{F(TO)}			0.27	V			
Forward slope resistance	r _t	$T_J = T_J$ maximum		8.72	mΩ			
Maximum junction capacitance per leg	CT	V _R = 5 V _{DC} (test signal ran	2800	pF				
Typical series inductance per leg	L _S	Measured lead to lead 5 n	8.0	nH				
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs			

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to 150	°C			
Maximum thermal resistance, junction to case per leg		Р	DC aparation	2.0				
Maximum thermal resistance, junction to case per package		R _{thJC}	DC operation	1.0	°C/W			
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth, and greased	0.50				
Approvimate weight				2	g			
Approximate weight				0.07	oz.			
Mounting torque	minimum			6 (5)	kgf ⋅ cm			
Mounting torque	maximum			12 (10)	(lbf · in)			
Marking davias			Case style D ² PAK (TO-263AB)	40CTC	045S			
Marking device			Case style TO-262AA	40CTQ	045-1			

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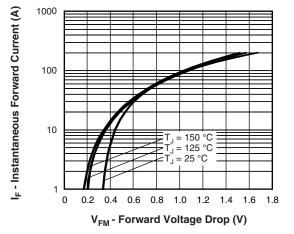
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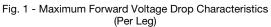
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VS-40CTQ045S-M3, VS-40CTQ045-1-M3

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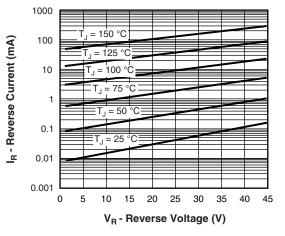


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

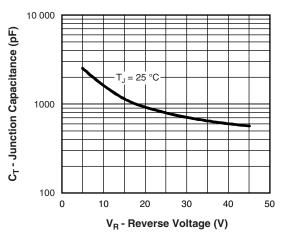


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

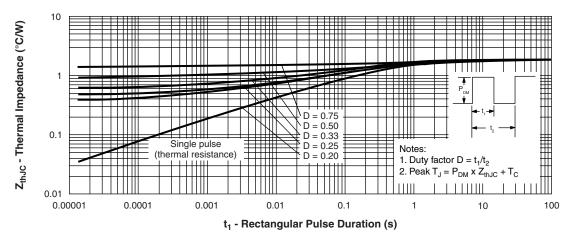
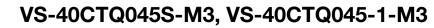


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

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 3
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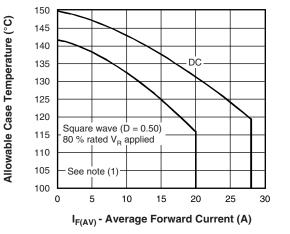
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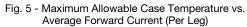
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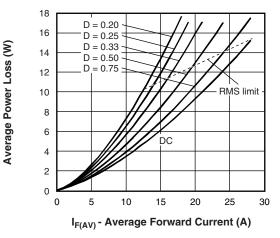


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

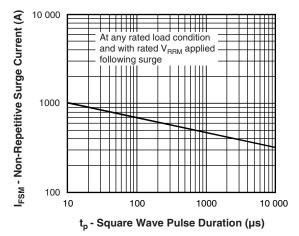


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

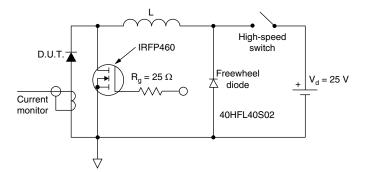


Fig. 8 - Unclamped Inductive Test Circuit

Note

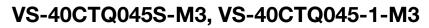
⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

Pd = forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}/D$) (see fig. 6); Pd_{BEV} = inverse power loss = $V_{B1} \times I_B (1 - D)$; I_B at $V_{B1} = 10 V$

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ORDERING INFORMATION TABLE

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SHAY

Device code	VS-	40	С	т	Q	045	S	TRL	-M3
		(2)	(3)	(4)	(5)	(6)	(7)	(8)	(9)
		\bigcirc	\bigcirc	\cup	0	\bigcirc	\bigcirc	\bigcirc	\bigcirc
			•	niconduo	•	oduct			
	2	- Cur	rrent rating (40 A)						
	3	- Circ	rcuit configuration: C = common cathode = TO-220						
	4	- T=	TO-220)					
	5	- Sch	ottky "G)" series					
	6	- Vol	tage rati	ng (045	= 45 V))			
	7	- •s	= D ² PA	К (ТО-2	263AB)				
		• -1	= TO-2	62AA					
	8	- • N	one = tu	ıbe					
		• T	RL = tap	be and r	eel (left	oriented	d - for D	² PAK (ГО-263
		• T	RR = ta	pe and r	eel (rigł	nt orient	ed - for	D ² PAK	(TO-26
	9			gen-free					

ORDERING INFORMATION									
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION							
VS-40CTQ045S-M3	50	Antistatic plastic tubes							
VS-40CTQ045STRL-M3	800	13" diameter plastic tape and reel							
VS-40CTQ045STRR-M3	800	13" diameter plastic tape and reel							
VS-40CTQ045-1-M3	50	Antistatic plastic tubes							

LINKS TO RELATED DOCUMENTS								
Dimensions	D ² PAK (TO-263AB)	www.vishay.com/doc?96164						
Dimensions	TO-262AA	www.vishay.com/doc?96165						
Part marking information	D ² PAK (TO-263AB)	www.vishay.com/doc?95444						
Part marking information	TO-262AA	www.vishay.com/doc?95443						
Packaging information		www.vishay.com/doc?96424						

Outline Dimensions



D²PAK

DIMENSIONS in millimeters and inches

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SHA



SYMBOL	MILLIM	MILLIMETERS		HES	NOTES	SYMBOL	MILLIM	IETERS	INC	HES	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inch

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

Revision: 08-Jul-15

1

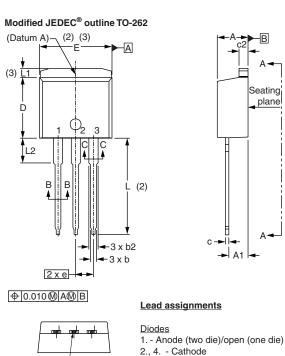
Outline Dimensions



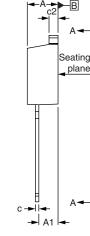
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TO-262

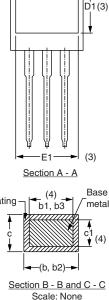
DIMENSIONS in millimeters and inches



Lead tip -



E1 Plating



Е

MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. А 4.06 4.83 0.160 0.190 2.03 A1 3.02 0.080 0.119 b 0.51 0.99 0.020 0.039 b1 0.51 0.89 0.020 0.035 4 b2 1.14 1.78 0.045 0.070 1.14 1.73 0.045 0.068 4 b3 0.38 0.74 0.015 0.029 С 0.38 0.58 0.015 0.023 4 c1 1.14 1.65 0.045 0.065 c2 D 8.51 9.65 0.335 0.380 2 D1 6.86 8.00 0.270 0.315 3 Е 9.65 10.67 0.380 0.420 2, 3 E1 7.90 8.80 0.311 0.346 3 0.100 BSC 2.54 BSC е L 13.46 14.10 0.530 0.555 L1 _ 1.65 0.065 3 _ 3.36 0.132 0.146 L2 3.71

3. - Anode

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

(5) Controlling dimension: inches

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

Outline conform to JEDEC TO-262 except A1 (maximum), (6) b (minimum), D1 (minimum) and L2 where dimensions derived the actual package outline

Revision: 11-Jul-2019

Document Number: 95419

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